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Applications of "<u>Embedded -</u> <u>Microcontrollers</u>"

Details

Product Status	Active
Core Processor	ARM® Cortex®-M4
Core Size	32-Bit Single-Core
Speed	50MHz
Connectivity	I ² C, IrDA, SPI, UART/USART, USB, USB OTG
Peripherals	DMA, I ² S, LVD, POR, PWM, WDT
Number of I/O	64
Program Memory Size	512KB (512K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	64K x 8
Voltage - Supply (Vcc/Vdd)	1.71V ~ 3.6V
Data Converters	A/D 20x16b; D/A 1x12b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 105°C (TA)
Mounting Type	Surface Mount
Package / Case	121-LFBGA
Supplier Device Package	121-MAPBGA (8x8)
Purchase URL	https://www.e-xfl.com/product-detail/nxp-semiconductors/mk21dn512avmc5r

Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong



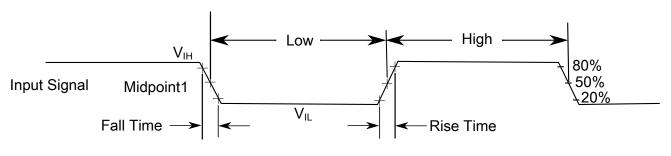
Symbol	Description	Min.	Max.	Unit
V _{DD}	Digital supply voltage	-0.3	3.8	V
I _{DD}	Digital supply current	—	155	mA
V _{DIO}	Digital input voltage (except RESET, EXTAL, and XTAL)	-0.3	V _{DD} + 0.3	V
V _{AIO}	Analog ¹ , RESET, EXTAL, and XTAL input voltage	-0.3	V _{DD} + 0.3	V
Ι _D	Maximum current single pin limit (applies to all digital pins)	-25	25	mA
V _{DDA}	Analog supply voltage	V _{DD} – 0.3	V _{DD} + 0.3	V
V _{USB0_DP}	USB0_DP input voltage	-0.3	3.63	V
V _{USB0_DM}	USB0_DM input voltage	-0.3	3.63	V
VREGIN	USB regulator input	-0.3	6.0	V
V _{BAT}	RTC battery supply voltage	-0.3	3.8	V

1. Analog pins are defined as pins that do not have an associated general purpose I/O port function.

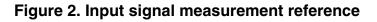
2 General

2.1 AC electrical characteristics

Unless otherwise specified, propagation delays are measured from the 50% to the 50% point, and rise and fall times are measured at the 20% and 80% points, as shown in the following figure.



The midpoint is V_{IL} + (V_{IH} - V_{IL}) / 2



2.2 Nonswitching electrical specifications



Symbol	Description	Min.	Max.	Unit	Notes
	• 2.7 V \leq V _{DD} \leq 3.6 V, I _{OH} = -2 mA	V _{DD} – 0.5	—	V	
	• 1.71 V \leq V _{DD} \leq 2.7 V, I _{OH} = -0.6 mA				
I _{OHT}	Output high current total for all ports	—	100	mA	
V _{OL}	Output low voltage — high drive strength				
	• 2.7 V \leq V _{DD} \leq 3.6 V, I _{OL} = 9 mA		0.5	V	
	• 1.71 V \leq V _{DD} \leq 2.7 V, I _{OL} = 3 mA		0.5	V	
	Output low voltage — low drive strength				
	• 2.7 V \leq V _{DD} \leq 3.6 V, I _{OL} = 2 mA		0.5	V	
	• 1.71 V \leq V _{DD} \leq 2.7 V, I _{OL} = 0.6 mA		0.5	V	
I _{OLT}	Output low current total for all ports	—	100	mA	
I _{IN}	Input leakage current (per pin)				
	@ full temperature range		1.0	μA	1
	• @ 25 °C		0.1	μΑ	
I _{OZ}	Hi-Z (off-state) leakage current (per pin)		1	μA	
I _{OZ}	Total Hi-Z (off-state) leakage current (all input pins)		4	μA	
R _{PU}	Internal pullup resistors	22	50	kΩ	2
R _{PD}	Internal pulldown resistors	22	50	kΩ	3

1. Tested by ganged leakage method

2. Measured at Vinput = V_{SS}

3. Measured at Vinput = V_{DD}

2.2.4 Power mode transition operating behaviors

All specifications except t_{POR} , and VLLSx \rightarrow RUN recovery times in the following table assume this clock configuration:

- CPU and system clocks = 50 MHz
- Bus clock = 50 MHz
- Flash clock = 25 MHz
- MCG mode: FEI

Table 5.	Power mode transition operating behaviors
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Symbol	Description	Min.	Max.	Unit	Notes
t _{POR}	After a POR event, amount of time from the point V_{DD} reaches 1.71 V to execution of the first instruction across the operating temperature range of the chip.	_	300	μs	1
	Table continues on the n	ext page			

Kinetis K21D Sub-Family Data Sheet, Rev6, 04/2014.



Symbol	Description	Min.	Max.	Unit	Notes
	 1.71 V/(V_{DD} slew rate) ≤ 300 μs 1.71 V/(V_{DD} slew rate) > 300 μs 	_	1.7 V / (V _{DD} slew rate)		
	• VLLS0 → RUN	_	150	μs	
	• VLLS1 → RUN	_	150	μs	
	• VLLS2 → RUN	_	79	μs	
	• VLLS3 → RUN	_	79	μs	
	• LLS → RUN	_	6	μs	
	• VLPS → RUN	—	5.2	μs	
	• STOP \rightarrow RUN		5.2	μs	

 Table 5. Power mode transition operating behaviors (continued)

1. Normal boot (FTFL_OPT[LPBOOT]=1)

2.2.5 Power consumption operating behaviors

Table 6. Power consumption operating behaviors

Symbol	Description	Min.	Тур.	Max.	Unit	Notes
I _{DDA}	Analog supply current		_	See note	mA	1
I _{DD_RUN}	Run mode current — all peripheral clocks disabled, code executing from flash					2
	• @ 1.8 V	_	12.98	14	mA	
	• @ 3.0 V	_	12.93	13.8	mA	
I _{DD_RUN}	Run mode current — all peripheral clocks enabled, code executing from flash					3, 4
	• @ 1.8 V	_	17.04	19.3	mA	
	• @ 3.0 V					
	• @ 25°C	_	17.01	18.9	mA	
	• @ 125°C	_	19.8	21.3	mA	
I _{DD_WAIT}	Wait mode high frequency current at 3.0 V — all peripheral clocks disabled	_	7.95	9.5	mA	2
I _{DD_WAIT}	Wait mode reduced frequency current at 3.0 V — all peripheral clocks disabled	_	5.88	7.4	mA	5
I _{DD_STOP}	Stop mode current at 3.0 V	_	320	436	μA	

Table continues on the next page ...



Symbol	Description	Min.	Тур.	Max.	Unit	Notes
	 @ 70°C @ 105°C 		15.20	25.3		
I _{DD_VBAT}	Average current when CPU is not accessing RTC registers at 3.0 V	_	0.91	1.1	μA	9
	• @ -40 to 25°C		1.1	1.35		
	• @ 50°C • @ 70°C		1.5	1.85		
	• @ 105°C		4.3	5.7		

Table 6. Power consumption operating behaviors (continued)

- 1. The analog supply current is the sum of the active or disabled current for each of the analog modules on the device. See each module's specification for its supply current.
- 2. 50 MHz core and system clock, 25 MHz bus clock, and 25 MHz flash clock. MCG configured for FEI mode. All peripheral clocks disabled.
- 3. 50 MHz core and system clock, 25 MHz bus clock, and 25 MHz flash clock. MCG configured for FEI mode. All peripheral clocks enabled, and peripherals are in active operation.
- 4. Max values are measured with CPU executing DSP instructions
- 5. 25 MHz core and system clock, 25 MHz bus clock, and 12.5 MHz flash clock. MCG configured for FEI mode.
- 6. 4 MHz core, system, and bus clock and 1 MHz flash clock. MCG configured for BLPE mode. All peripheral clocks disabled. Code executing from flash.
- 7. 4 MHz core, system, and bus clock and 1 MHz flash clock. MCG configured for BLPE mode. All peripheral clocks enabled but peripherals are not in active operation. Code executing from flash.
- 8. 4 MHz core, system, and bus clock and 1 MHz flash clock. MCG configured for BLPE mode. All peripheral clocks disabled.
- 9. Includes 32 kHz oscillator current and RTC operation.

2.2.5.1 Diagram: Typical IDD_RUN operating behavior

The following data was measured under these conditions:

- MCG in FBE mode
- USB regulator disabled
- No GPIOs toggled
- Code execution from flash with cache enabled
- For the ALLOFF curve, all peripheral clocks are disabled except FTFL



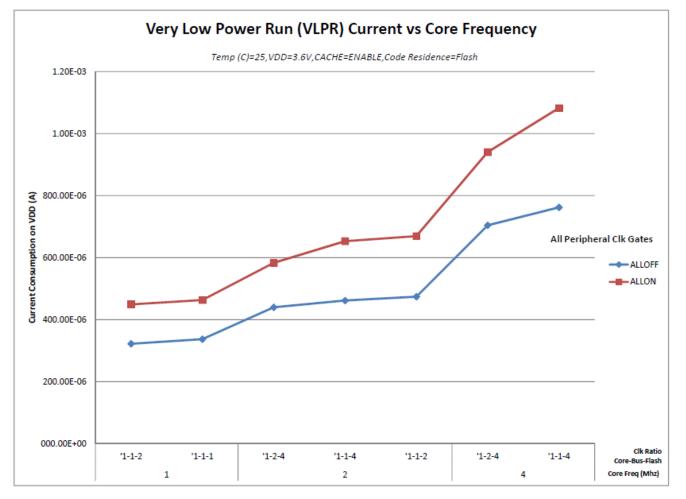


Figure 4. VLPR mode supply current vs. core frequency

2.2.6 EMC radiated emissions operating behaviors

Table 7. EMC radiated emissions operating behaviors 1

Symbol	Description	Frequency band (MHz)	Тур.	Unit	Notes
V _{RE1}	Radiated emissions voltage, band 1	0.15–50	19	dBµV	2, 3
V _{RE2}	Radiated emissions voltage, band 2	50–150	21	dBµV	
V _{RE3}	Radiated emissions voltage, band 3	150–500	19	dBµV	
V _{RE4}	Radiated emissions voltage, band 4	500-1000	11	dBµV	
V _{RE_IEC}	IEC level	0.15–1000	L		3, 4

1. This data was collected on a MK20DN128VLH5 64pin LQFP device.

2. Determined according to IEC Standard 61967-1, Integrated Circuits - Measurement of Electromagnetic Emissions, 150 kHz to 1 GHz Part 1: General Conditions and Definitions and IEC Standard 61967-2, Integrated Circuits - Measurement of Electromagnetic Emissions, 150 kHz to 1 GHz Part 2: Measurement of Radiated Emissions—TEM Cell and



Symbol	Description	Min.	Max.	Unit	Notes
f _{FLASH}	Flash clock	—	1	MHz	
f _{ERCLK}	External reference clock	—	16	MHz	
f _{LPTMR_pin}	LPTMR clock	—	25	MHz	
f _{LPTMR_ERCLK}	LPTMR external reference clock	—	16	MHz	
f _{I2S_MCLK}	I2S master clock	_	12.5	MHz	
f _{I2S_BCLK}	I2S bit clock		4	MHz	

Table 9. Device clock specifications (continued)

1. The frequency limitations in VLPR mode here override any frequency specification listed in the timing specification for any other module.

2.3.2 General switching specifications

These general purpose specifications apply to all pins configured for:

- GPIO signaling
- Other peripheral module signaling not explicitly stated elsewhere

Symbol	Description	Min.	Max.	Unit	Notes
	GPIO pin interrupt pulse width (digital glitch filter disabled) — Synchronous path	1.5	_	Bus clock cycles	1, 2
	GPIO pin interrupt pulse width (digital glitch filter disabled, analog filter enabled) — Asynchronous path	100	_	ns	3
	GPIO pin interrupt pulse width (digital glitch filter disabled, analog filter disabled) — Asynchronous path	50	-	ns	3
	External reset pulse width (digital glitch filter disabled)	100	_	ns	3
	Port rise and fall time (high drive strength)				4
	Slew disabled				
	• $1.71 \le V_{DD} \le 2.7V$	—	13	ns	
	• $2.7 \le V_{DD} \le 3.6V$	—	7	ns	
	Slew enabled				
	• $1.71 \le V_{DD} \le 2.7V$	—	36	ns	
	• $2.7 \le V_{DD} \le 3.6V$	—	24	ns	
	Port rise and fall time (low drive strength)				5
	Slew disabled				
	• $1.71 \le V_{DD} \le 2.7V$	_	12	ns	
	• $2.7 \le V_{DD} \le 3.6V$	_	6	ns	
	Slew enabled				
		_	36	ns	

Table 10. General switching specifications



Peripheral operating requirements and behaviors

Board type	Symbol	Description	121 MAPBGA	Unit	Notes
Four-layer (2s2p)	R _{ejma}	Thermal resistance, junction to ambient (200 ft./ min. air speed)	42	°C/W	1,3
_	R _{θJB}	Thermal resistance, junction to board	29	°C/W	4
_	R _{θJC}	Thermal resistance, junction to case	21	°C/W	5
	Ψ _{JT}	Thermal characterization parameter, junction to package top outside center (natural convection)	4	°C/W	6

NOTES:

- 1. Junction temperature is a function of die size, on-chip power dissipation, package thermal resistance, mounting site (board) temperature, ambient temperature, air flow, power dissipation of other components on the board, and board thermal resistance.
- 2. Determined according to JEDEC Standard JESD51-2, *Integrated Circuits Thermal Test Method Environmental Conditions—Natural Convection (Still Air)* with the single layer board horizontal. Board meets JESD51-9 specification.
- 3. Determined according to JEDEC Standard JESD51-6, *Integrated Circuit Thermal Test Method Environmental Conditions—Forced Convection (Moving Air)* with the board horizontal.
- 4. Determined according to JEDEC Standard JESD51-8, *Integrated Circuit Thermal Test Method Environmental Conditions—Junction-to-Board*. Board temperature is measured on the top surface of the board near the package.
- 5. Determined according to Method 1012.1 of MIL-STD 883, *Test Method Standard*, *Microcircuits*, with the cold plate temperature used for the case temperature. The value includes the thermal resistance of the interface material between the top of the package and the cold plate.
- 6. Determined according to JEDEC Standard JESD51-2, *Integrated Circuits Thermal Test Method Environmental Conditions—Natural Convection (Still Air)*.

3 Peripheral operating requirements and behaviors



Symbol	Description	Min.	Тур.	Max.	Unit	Notes
	• 32 kHz	—	5	—	μA	
	• 4 MHz	—	500	_	μA	
	• 8 MHz (RANGE=01)	—	600	_	μA	
	• 16 MHz	—	2.5	_	mA	
	• 24 MHz	_	3	_	mA	
	• 32 MHz	_	4	_	mA	
C _x	EXTAL load capacitance		_	_		2, 3
Cy	XTAL load capacitance	_	—	—		2, 3
R _F	Feedback resistor — low-frequency, low-power mode (HGO=0)	_	—	—	MΩ	2, 4
	Feedback resistor — low-frequency, high-gain mode (HGO=1)	_	10	_	MΩ	
	Feedback resistor — high-frequency, low-power mode (HGO=0)	—	—		MΩ	
	Feedback resistor — high-frequency, high-gain mode (HGO=1)	—	1	_	MΩ	
R _S	Series resistor — low-frequency, low-power mode (HGO=0)	—	_		kΩ	
	Series resistor — low-frequency, high-gain mode (HGO=1)	_	200		kΩ	
	Series resistor — high-frequency, low-power mode (HGO=0)	—	_		kΩ	
	Series resistor — high-frequency, high-gain mode (HGO=1)					
		—	0	_	kΩ	
V _{pp} ⁵	Peak-to-peak amplitude of oscillation (oscillator mode) — low-frequency, low-power mode (HGO=0)	_	0.6	_	V	
	Peak-to-peak amplitude of oscillation (oscillator mode) — low-frequency, high-gain mode (HGO=1)	_	V _{DD}	_	V	
	Peak-to-peak amplitude of oscillation (oscillator mode) — high-frequency, low-power mode (HGO=0)	_	0.6	_	V	
	Peak-to-peak amplitude of oscillation (oscillator mode) — high-frequency, high-gain mode (HGO=1)		V _{DD}	_	V	

Table 15. Oscillator DC electrical specifications (continued)

- 1. V_{DD}=3.3 V, Temperature =25 °C
- 2. See crystal or resonator manufacturer's recommendation
- 3. C_x and C_y can be provided by using either integrated capacitors or external components.
- 4. When low-power mode is selected, R_F is integrated and must not be attached externally.
- 5. The EXTAL and XTAL pins should only be connected to required oscillator components and must not be connected to any other device.

Symbol	Description	Min.	Тур.	Max.	Unit	Notes
$f_{osc_{lo}}$	Oscillator crystal or resonator frequency — low- frequency mode (MCG_C2[RANGE]=00)	32	—	40	kHz	
f _{osc_hi_1}	Oscillator crystal or resonator frequency — high- frequency mode (low range) (MCG_C2[RANGE]=01)	3	_	8	MHz	
f _{osc_hi_2}	Oscillator crystal or resonator frequency — high frequency mode (high range) (MCG_C2[RANGE]=1x)	8	_	32	MHz	
f _{ec_extal}	Input clock frequency (external clock mode)		_	50	MHz	1, 2
t _{dc_extal}	Input clock duty cycle (external clock mode)	40	50	60	%	
t _{cst}	Crystal startup time — 32 kHz low-frequency, low-power mode (HGO=0)	—	750		ms	3, 4
	Crystal startup time — 32 kHz low-frequency, high-gain mode (HGO=1)	—	250	_	ms	
	Crystal startup time — 8 MHz high-frequency (MCG_C2[RANGE]=01), low-power mode (HGO=0)	_	0.6	_	ms	
	Crystal startup time — 8 MHz high-frequency (MCG_C2[RANGE]=01), high-gain mode (HGO=1)	_	1	_	ms	

3.3.2.2 Oscillator frequency specifications Table 16. Oscillator frequency specifications

1. Other frequency limits may apply when external clock is being used as a reference for the FLL or PLL.

2. When transitioning from FEI or FBI to FBE mode, restrict the frequency of the input clock so that, when it is divided by FRDIV, it remains within the limits of the DCO input clock frequency.

3. Proper PC board layout procedures must be followed to achieve specifications.

Crystal startup time is defined as the time between the oscillator being enabled and the OSCINIT bit in the MCG_S
register being set.

NOTE

The 32 kHz oscillator works in low power mode by default and cannot be moved into high power/gain mode.

3.3.3 32 kHz oscillator electrical characteristics

3.3.3.1 32 kHz oscillator DC electrical specifications Table 17. 32kHz oscillator DC electrical specifications

		-			
Symbol	Description	Min.	Тур.	Max.	Unit
V _{BAT}	Supply voltage	1.71	_	3.6	V

Table continues on the next page...



Symbol	Description	Min.	Тур.	Max.	Unit	Notes
t _{eewr8bers}	Byte-write to erased FlexRAM location execution time	_	175	260	μs	3
	Byte-write to FlexRAM execution time:					—
t _{eewr8b32k}	32 KB EEPROM backup	_	385	1800	μs	
t _{eewr8b64k}	64 KB EEPROM backup		475	2000	μs	
	Word-write to FlexRAM	for EEPRON	A operation			
t _{eewr16bers}	Word-write to erased FlexRAM location execution time	_	175	260	μs	_
	Word-write to FlexRAM execution time:					—
t _{eewr16b32k}	32 KB EEPROM backup	—	385	1800	μs	
t _{eewr16b64k}	64 KB EEPROM backup	_	475	2000	μs	
	Longword-write to FlexRA	M for EEPR	OM operatio	n	I	
t _{eewr32bers}	Longword-write to erased FlexRAM location execution time	_	360	540	μs	_
	Longword-write to FlexRAM execution time:					_
t _{eewr32b32k}	32 KB EEPROM backup	_	630	2050	μs	
t _{eewr32b64k}	64 KB EEPROM backup	_	810	2250	μs	

Table 20.	Flash command	timing s	specifications ((continued)	

1. Assumes 25 MHz flash clock frequency.

2. Maximum times for erase parameters based on expectations at cycling end-of-life.

3. For byte-writes to an erased FlexRAM location, the aligned word containing the byte must be erased.

3.4.1.3 Flash high voltage current behaviors Table 21. Flash high voltage current behaviors

Symbol	Description	Min.	Тур.	Max.	Unit
I _{DD_PGM}	Average current adder during high voltage flash programming operation		2.5	6.0	mA
I _{DD_ERS}	Average current adder during high voltage flash erase operation		1.5	4.0	mA

3.4.1.4 Reliability specifications Table 22. NVM reliability specifications

Symbol	Description	Min.	Typ. ¹	Max.	Unit	Notes	
Program Flash							
t _{nvmretp10k}	Data retention after up to 10 K cycles	5	50	_	years	_	
t _{nvmretp1k}	Data retention after up to 1 K cycles	20	100		years		

Table continues on the next page...



3.6.2 CMP and 6-bit DAC electrical specifications Table 26. Comparator and 6-bit DAC electrical specifications

Symbol	Description	Min.	Тур.	Max.	Unit
V_{DD}	Supply voltage	1.71	—	3.6	V
IDDHS	Supply current, High-speed mode (EN=1, PMODE=1)	—	_	200	μA
I _{DDLS}	Supply current, low-speed mode (EN=1, PMODE=0)	—	—	20	μA
V _{AIN}	Analog input voltage	$V_{SS} - 0.3$	—	V _{DD}	V
V _{AIO}	Analog input offset voltage	—	—	20	mV
V _H	Analog comparator hysteresis ¹				
	• CR0[HYSTCTR] = 00	_	5	_	mV
	• CR0[HYSTCTR] = 01		10	_	mV
	• CR0[HYSTCTR] = 10	—	20	_	mV
	• CR0[HYSTCTR] = 11	_	30	_	mV
V _{CMPOh}	Output high	V _{DD} – 0.5			V
V _{CMPOI}	Output low		_	0.5	V
t _{DHS}	Propagation delay, high-speed mode (EN=1, PMODE=1)	20	50	200	ns
t _{DLS}	Propagation delay, low-speed mode (EN=1, PMODE=0)	80	250	600	ns
	Analog comparator initialization delay ²		_	40	μs
I _{DAC6b}	6-bit DAC current adder (enabled)		7	—	μA
INL	6-bit DAC integral non-linearity	-0.5	—	0.5	LSB ³
DNL	6-bit DAC differential non-linearity	-0.3	_	0.3	LSB

1. Typical hysteresis is measured with input voltage range limited to 0.6 to V_{DD} -0.6 V.

 Comparator initialization delay is defined as the time between software writes to change control inputs (Writes to CMP_DACCR[DACEN], CMP_DACCR[VRSEL], CMP_DACCR[VOSEL], CMP_MUXCR[PSEL], and CMP_MUXCR[MSEL]) and the comparator output settling to a stable level.

3. 1 LSB = $V_{reference}/64$



Peripheral operating requirements and behaviors

Symbol	Description	Min.	Тур.	Max.	Unit	Notes
V _{out}	Voltage reference output with factory trim at nominal V_{DDA} and temperature=25C	1.1915	1.195	1.1977	V	1
V _{out}	Voltage reference output — factory trim	1.1584	—	1.2376	V	1
V _{out}	Voltage reference output — user trim	1.193	_	1.197	V	1
V _{step}	Voltage reference trim step	_	0.5	—	mV	1
V _{tdrift}	Temperature drift (Vmax -Vmin across the full temperature range)	—	_	80	mV	1
I _{bg}	Bandgap only current	_	—	80	μA	1
ΔV_{LOAD}	Load regulation • current = ± 1.0 mA	_	200	_	μV	1, 2
T _{stup}	Buffer startup time			100	μs	_
V _{vdrift}	Voltage drift (Vmax -Vmin across the full voltage range)	—	2	-	mV	1

Table 30. VREF full-range operating behaviors

1. See the chip's Reference Manual for the appropriate settings of the VREF Status and Control register.

2. Load regulation voltage is the difference between the VREF_OUT voltage with no load vs. voltage with defined load

Table 31. VREF limited-range operating requirements

Symbol	Description	Min.	Max.	Unit	Notes
T _A	Temperature	0	50	°C	

Table 32. VREF limited-range operating behaviors

Symbol	Description	Min.	Max.	Unit	Notes
V _{out}	Voltage reference output with factory trim	1.173	1.225	V	_

3.7 Timers

See General switching specifications.

3.8 Communication interfaces



Peripheral operating requirements and behaviors

Symbol	Description	Min.	Typ. ¹	Max.	Unit	Notes
	Run mode	3	3.3	3.6	V	
	Standby mode	2.1	2.8	3.6	V	
V _{Reg33out}	Regulator output voltage — Input supply (VREGIN) < 3.6 V, pass-through mode	2.1	_	3.6	V	2
C _{OUT}	External output capacitor	1.76	2.2	8.16	μF	
ESR	External output capacitor equivalent series resistance	1	_	100	mΩ	
I _{LIM}	Short circuit current	—	290	—	mA	

1. Typical values assume VREGIN = 5.0 V, Temp = 25 $^{\circ}$ C unless otherwise stated.

2. Operating in pass-through mode: regulator output voltage equal to the input voltage minus a drop proportional to I_{Load}.

3.8.4 DSPI switching specifications (limited voltage range)

The DMA Serial Peripheral Interface (DSPI) provides a synchronous serial bus with master and slave operations. Many of the transfer attributes are programmable. The tables below provide DSPI timing characteristics for classic SPI timing modes. Refer to the DSPI chapter of the Reference Manual for information on the modified transfer formats used for communicating with slower peripheral devices.

Table 35. Master mode DSPI timing (limited voltage range)

Num	Description	Min.	Max.	Unit	Notes
	Operating voltage	2.7	3.6	V	
	Frequency of operation	_	25	MHz	
DS1	DSPI_SCK output cycle time	2 x t _{BUS}	—	ns	
DS2	DSPI_SCK output high/low time	(t _{SCK} /2) – 2	(t _{SCK} /2) + 2	ns	
DS3	DSPI_PCSn valid to DSPI_SCK delay	(t _{BUS} x 2) – 2	_	ns	1
DS4	DSPI_SCK to DSPI_PCSn invalid delay	(t _{BUS} x 2) – 2	_	ns	2
DS5	DSPI_SCK to DSPI_SOUT valid	_	8.5	ns	
DS6	DSPI_SCK to DSPI_SOUT invalid	-2	_	ns	
DS7	DSPI_SIN to DSPI_SCK input setup	15	—	ns	
DS8	DSPI_SCK to DSPI_SIN input hold	0	_	ns	

1. The delay is programmable in SPIx_CTARn[PSSCK] and SPIx_CTARn[CSSCK].

2. The delay is programmable in SPIx_CTARn[PASC] and SPIx_CTARn[ASC].



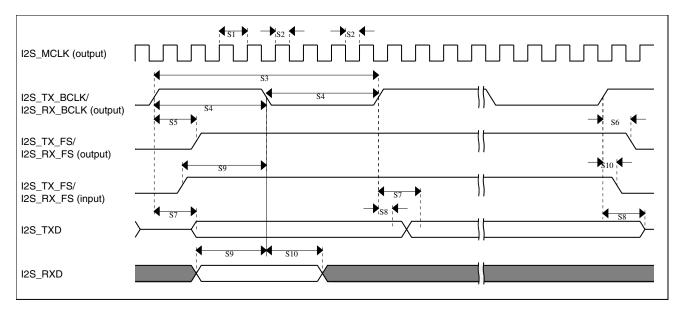
3.8.8 I2S switching specifications

3.8.8.1 Normal Run, Wait and Stop mode performance over the full operating voltage range

This section provides the operating performance over the full operating voltage for the device in Normal Run, Wait and Stop modes.

Num.	Characteristic	Min.	Max.	Unit
	Operating voltage	1.71	3.6	V
S1	I2S_MCLK cycle time	40	_	ns
S2	I2S_MCLK (as an input) pulse width high/low	45%	55%	MCLK period
S3	I2S_TX_BCLK/I2S_RX_BCLK cycle time (output)	80	_	ns
S4	I2S_TX_BCLK/I2S_RX_BCLK pulse width high/low	45%	55%	BCLK period
S5	I2S_TX_BCLK/I2S_RX_BCLK to I2S_TX_FS/ I2S_RX_FS output valid	—	15	ns
S6	I2S_TX_BCLK/I2S_RX_BCLK to I2S_TX_FS/ I2S_RX_FS output invalid	0	-	ns
S7	I2S_TX_BCLK to I2S_TXD valid	_	15	ns
S8	I2S_TX_BCLK to I2S_TXD invalid	0	_	ns
S9	I2S_RXD/I2S_RX_FS input setup before I2S_RX_BCLK	25	—	ns
S10	I2S_RXD/I2S_RX_FS input hold after I2S_RX_BCLK	0	—	ns

Table 39.	I2S/SAI	master	mode	timina







Num.	Characteristic	Min.	Max.	Unit
	Operating voltage	1.71	3.6	V
S1	I2S_MCLK cycle time	62.5	—	ns
S2	I2S_MCLK pulse width high/low	45%	55%	MCLK period
S3	I2S_TX_BCLK/I2S_RX_BCLK cycle time (output)	250	_	ns
S4	I2S_TX_BCLK/I2S_RX_BCLK pulse width high/low	45%	55%	BCLK period
S5	I2S_TX_BCLK/I2S_RX_BCLK to I2S_TX_FS/ I2S_RX_FS output valid	—	45	ns
S6	I2S_TX_BCLK/I2S_RX_BCLK to I2S_TX_FS/ I2S_RX_FS output invalid	0	—	ns
S7	I2S_TX_BCLK to I2S_TXD valid	_	45	ns
S8	I2S_TX_BCLK to I2S_TXD invalid	0	—	ns
S9	I2S_RXD/I2S_RX_FS input setup before I2S_RX_BCLK	75	—	ns
S10	I2S_RXD/I2S_RX_FS input hold after I2S_RX_BCLK	0	—	ns

Table 41. I2S/SAI master mode timing in VLPR, VLPW, and VLPS modes
(full voltage range)

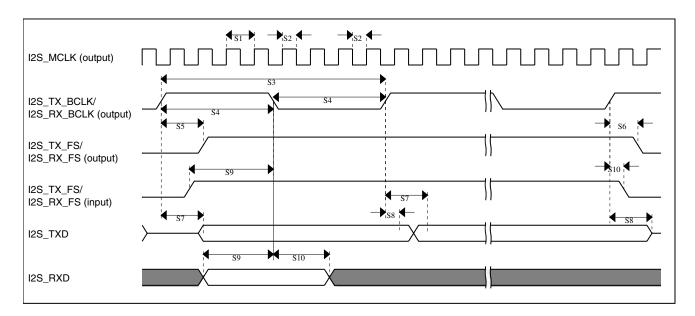


Figure 23. I2S/SAI timing — master modes

Table 42.I2S/SAI slave mode timing in VLPR, VLPW, and VLPS modes (full
voltage range)

Num.	Characteristic	Min.	Max.	Unit
	Operating voltage	1.71	3.6	V
S11	I2S_TX_BCLK/I2S_RX_BCLK cycle time (input)	250	_	ns

Table continues on the next page...

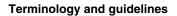
121 Map	Default	ALTO	ALT1	ALT2	ALT3	ALT4	ALT5	ALT6	ALT7	EzPort
BGA										
E4	ADC0_SE10	ADC0_SE10	PTE0	SPI1_PCS1	UART1_TX		TRACE_ CLKOUT	I2C1_SDA	RTC_CLKOUT	
E3	ADC0_SE11	ADC0_SE11	PTE1/ LLWU_P0	SPI1_SOUT	UART1_RX		TRACE_D3	I2C1_SCL	SPI1_SIN	
E2	ADC0_DP1	ADC0_DP1	PTE2/ LLWU_P1	SPI1_SCK	UART1_CTS_b		TRACE_D2			
F4	ADC0_DM1	ADC0_DM1	PTE3	SPI1_SIN	UART1_RTS_b		TRACE_D1		SPI1_SOUT	
H7	DISABLED		PTE4/ LLWU_P2	SPI1_PCS0	UART3_TX		TRACE_D0			
G4	DISABLED		PTE5	SPI1_PCS2	UART3_RX					
E6	VDD	VDD								
G7	VSS	VSS								
K3	ADC0_SE4a	ADC0_SE4a	PTE16	SPI0_PCS0	UART2_TX	FTM_CLKIN0		FTM0_FLT3		
H4	ADC0_SE5a	ADC0_SE5a	PTE17	SPI0_SCK	UART2_RX	FTM_CLKIN1		LPTMR0_ALT3		
A11	ADC0_SE6a	ADC0_SE6a	PTE18	SPI0_SOUT	UART2_CTS_b	I2C0_SDA				
A10	ADC0_SE7a	ADC0_SE7a	PTE19	SPI0_SIN	UART2_RTS_b	I2C0_SCL				
L6	VSS	VSS								
F1	USB0_DP	USB0_DP								
F2	USB0_DM	USB0_DM								
G1	VOUT33	VOUT33								
G2	VREGIN	VREGIN								
K1	ADC0_DP0	ADC0_DP0								
K2	ADC0_DM0	ADC0_DM0								
L1	ADC0_DP3	ADC0_DP3								
L2	ADC0_DM3	ADC0_DM3								
F5	VDDA	VDDA								
G5	VREFH	VREFH								
G6	VREFL	VREFL								
F6	VSSA	VSSA								
L3	VREF_OUT/ CMP1_IN5/ CMP0_IN5	VREF_OUT/ CMP1_IN5/ CMP0_IN5								
K5	DAC0_OUT/ CMP1_IN3/ ADC0_SE23	DAC0_OUT/ CMP1_IN3/ ADC0_SE23								
L7	TAMPER0/ RTC_ WAKEUP_B	TAMPER0/ RTC_ WAKEUP_B								
H5	TAMPER1	TAMPER1								
J5	TAMPER2	TAMPER2								
L4	XTAL32	XTAL32								
L5	EXTAL32	EXTAL32								



Pinout

121 Map Bga	Default	ALTO	ALT1	ALT2	ALT3	ALT4	ALT5	ALT6	ALT7	EzPort
K6	VBAT	VBAT								
J6	JTAG_TCLK/ SWD_CLK/ EZP_CLK		PTA0	UART0_CTS_ b/ UART0_COL_b	FTM0_CH5				JTAG_TCLK/ SWD_CLK	EZP_CLK
H8	JTAG_TDI/ EZP_DI		PTA1	UART0_RX	FTM0_CH6				JTAG_TDI	EZP_DI
J7	JTAG_TDO/ TRACE_SWO/ EZP_DO		PTA2	UART0_TX	FTM0_CH7				JTAG_TDO/ TRACE_SWO	EZP_DO
H9	JTAG_TMS/ SWD_DIO		PTA3	UART0_RTS_b	FTM0_CH0				JTAG_TMS/ SWD_DIO	
J8	NMI_b/ EZP_CS_b		PTA4/ LLWU_P3		FTM0_CH1				NMI_b	EZP_CS_b
K7	DISABLED		PTA5	USB_CLKIN	FTM0_CH2			I2S0_TX_BCLK	JTAG_TRST_b	
K8	DISABLED		PTA12		FTM1_CH0			I2S0_TXD0	FTM1_QD_ PHA	
L8	DISABLED		PTA13/ LLWU_P4		FTM1_CH1			I2S0_TX_FS	FTM1_QD_ PHB	
K9	DISABLED		PTA14	SPI0_PCS0	UART0_TX			I2S0_RX_ BCLK	12S0_TXD1	
L9	DISABLED		PTA15	SPI0_SCK	UART0_RX			I2S0_RXD0		
J10	DISABLED		PTA16	SPI0_SOUT	UART0_CTS_ b/ UART0_COL_b			12S0_RX_FS	I2S0_RXD1	
H10	DISABLED		PTA17	SPI0_SIN	UART0_RTS_b			I2S0_MCLK		
L10	VDD	VDD								
K10	VSS	VSS								
L11	EXTAL0	EXTAL0	PTA18		FTM0_FLT2	FTM_CLKIN0				
K11	XTAL0	XTAL0	PTA19		FTM1_FLT0	FTM_CLKIN1		LPTMR0_ALT1		
J11	RESET_b	RESET_b								
G11	ADC0_SE8	ADC0_SE8	PTB0/ LLWU_P5	I2C0_SCL	FTM1_CH0			FTM1_QD_ PHA		
G10	ADC0_SE9	ADC0_SE9	PTB1	I2C0_SDA	FTM1_CH1			FTM1_QD_ PHB		
G9	ADC0_SE12	ADC0_SE12	PTB2	I2C0_SCL	UART0_RTS_b			FTM0_FLT3		
G8	ADC0_SE13	ADC0_SE13	PTB3	I2C0_SDA	UART0_CTS_ b/ UART0_COL_b			FTM0_FLT0		
D10	DISABLED		PTB10	SPI1_PCS0	UART3_RX			FTM0_FLT1		
C10	DISABLED		PTB11	SPI1_SCK	UART3_TX			FTM0_FLT2		
B11	DISABLED		PTB12	UART3_RTS_b	FTM1_CH0	FTM0_CH4		FTM1_QD_ PHA		
C11	DISABLED		PTB13	UART3_CTS_b	FTM1_CH1	FTM0_CH5		FTM1_QD_ PHB		

121 Map Bga	Default	ALTO	ALT1	ALT2	ALT3	ALT4	ALT5	ALT6	ALT7	EzPort
B10	DISABLED		PTB16	SPI1_SOUT	UART0_RX			EWM_IN	FTM_CLKIN0	
E9	DISABLED		PTB17	SPI1_SIN	UART0_TX			EWM_OUT_b	FTM_CLKIN1	
D9	DISABLED		PTB18		FTM2_CH0	I2S0_TX_BCLK				
C9	DISABLED		PTB19		FTM2_CH1	I2S0_TX_FS				
B9	ADC0_SE14	ADC0_SE14	PTC0	SPI0_PCS4	PDB0_EXTRG			I2S0_TXD1		
D8	ADC0_SE15	ADC0_SE15	PTC1/ LLWU_P6	SPI0_PCS3	UART1_RTS_b	FTM0_CH0		12S0_TXD0		
C8	ADC0_SE4b/ CMP1_IN0	ADC0_SE4b/ CMP1_IN0	PTC2	SPI0_PCS2	UART1_CTS_b	FTM0_CH1		12S0_TX_FS		
B8	CMP1_IN1	CMP1_IN1	PTC3/ LLWU_P7	SPI0_PCS1	UART1_RX	FTM0_CH2	CLKOUT	I2S0_TX_BCLK		
G3	VSS	VSS								
E5	VDD	VDD								
A8	DISABLED		PTC4/ LLWU_P8	SPI0_PCS0	UART1_TX	FTM0_CH3		CMP1_OUT		
D7	DISABLED		PTC5/ LLWU_P9	SPI0_SCK	LPTMR0_ALT2	12S0_RXD0		CMP0_OUT	FTM0_CH2	
C7	CMP0_IN0	CMP0_IN0	PTC6/ LLWU_P10	SPI0_SOUT	PDB0_EXTRG	12S0_RX_ BCLK		I2S0_MCLK		
B7	CMP0_IN1	CMP0_IN1	PTC7	SPI0_SIN	USB_SOF_ OUT	I2S0_RX_FS				
A7	CMP0_IN2	CMP0_IN2	PTC8			I2S0_MCLK				
D6	CMP0_IN3	CMP0_IN3	PTC9			I2S0_RX_ BCLK		FTM2_FLT0		
C6	DISABLED		PTC10	I2C1_SCL		I2S0_RX_FS				
C5	DISABLED		PTC11/ LLWU_P11	I2C1_SDA		I2S0_RXD1				
B6	DISABLED		PTC12							
A6	DISABLED		PTC13							
D5	DISABLED		PTC16		UART3_RX					
C4	DISABLED		PTC17		UART3_TX					
D4	DISABLED		PTD0/ LLWU_P12	SPI0_PCS0	UART2_RTS_b					
D3	ADC0_SE5b	ADC0_SE5b	PTD1	SPI0_SCK	UART2_CTS_b					
C3	DISABLED		PTD2/ LLWU_P13	SPI0_SOUT	UART2_RX	I2C0_SCL				
B3	DISABLED		PTD3	SPI0_SIN	UART2_TX	I2C0_SDA				
A3	ADC0_SE21	ADC0_SE21	PTD4/ LLWU_P14	SPI0_PCS1	UART0_RTS_b	FTM0_CH4		EWM_IN		
A2	ADC0_SE6b	ADC0_SE6b	PTD5	SPI0_PCS2	UART0_CTS_ b/ UART0_COL_b	FTM0_CH5		EWM_OUT_b		





8.2 Definition: Operating behavior

An *operating behavior* is a specified value or range of values for a technical characteristic that are guaranteed during operation if you meet the operating requirements and any other specified conditions.

8.2.1 Example

This is an example of an operating behavior:

Symbol	Description	Min.	Max.	Unit
•••	Digital I/O weak pullup/ pulldown current	10	130	μΑ

8.3 Definition: Attribute

An *attribute* is a specified value or range of values for a technical characteristic that are guaranteed, regardless of whether you meet the operating requirements.

8.3.1 Example

This is an example of an attribute:

Symbol	Description	Min.	Max.	Unit
CIN_D	Input capacitance: digital pins	—	7	pF

8.4 Definition: Rating

A *rating* is a minimum or maximum value of a technical characteristic that, if exceeded, may cause permanent chip failure:

- Operating ratings apply during operation of the chip.
- *Handling ratings* apply when the chip is not powered.



Symbol	Description	Value	Unit
T _A	Ambient temperature	25	C°
V _{DD}	3.3 V supply voltage	3.3	V

9 Revision History

The following table provides a revision history for this document.

Rev. No.	Date	Substantial Changes	
1	6/2012	Alpha customer release.	
2	7/2012	 Updated section "Power consumption operating behaviors". Updated section "Flash timing specifications — program and erase". Updated section "Flash timing specifications — commands". Removed the 32K ratio from "Write endurance" in section "Reliability specifications". Updated IDDstby maximum value in section "VREG electrical specifications". Added the charts in section "Diagram: Typical IDD_RUN operating behavior". 	
3	8/2012	 Updated section "Power consumption operating behaviors". Updated section "EMC radiated emissions operating behaviors". Updated section "MCG specifications". Added applicable notes in section "Signal Multiplexing and Pin Assignments". 	
4	12/2012	 Updated section "Power consumption operating behaviors" Updated section "MCG specifications" Updated section "16-bit ADC operating conditions" Added section "Small package marking" 	
5	01/2014	 Updated supported part numbers. Updated section "Power mode transition operating behaviors" Updated section "MCG specifications" Updated section "Oscillator DC electrical specifications" Updated section "Oscillator frequency specifications" 	
6	03/2014	Initial public release	

Table 43. Revision History